

P-Channel 200 V (D-S) Power MOSFET

PRODUCT SUMMARY

V _{DS} (V)	R _{DS(on)} (Ω)(Max.)	I _D (A) ^a	Q _g (Max.)
- 200	0.5 at V _{GS} = - 10 V	- 10	32 nC

FEATURES

- DT-Trench Power MOSFET
- 100 % UIS Tested
- Fast switching

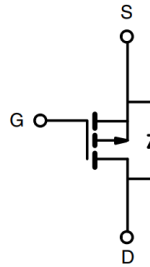
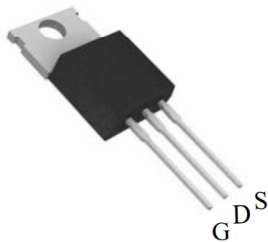
APPLICATIONS

- Load Switch



RoHS
COMPLIANT

TO-220 Pin Configuration



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-Source Voltage	V _{DS}	-200	V	
Gate-Source Voltage	V _{GS}	± 20		
Continuous Drain Current ^d (T _J = 175 °C)	I _D	T _C = 25 °C	A	
		T _C = 100 °C		-6.6
Pulsed Drain Current	I _{DM}	-40	mJ	
Avalanche Current	I _{AS}	-38		
Single Pulse Avalanche Energy ^a	E _{AS}	713		
Power Dissipation	P _D	T _C = 25 °C ^c	128	W
		T _A = 25 °C ^b	4.86	
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS

PARAMETER	SYMBOL	MAX.	UNIT
Junction-to-Ambient	R _{thJA}	62	°C/W
Junction-to-Case	R _{thJC}	1.0	

Notes

- Duty cycle ≤ 1 %.
- When mounted on 1" square PCB (FR4 material).
- See SOA curve for voltage derating.

SPECIFICATIONS ($T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted)

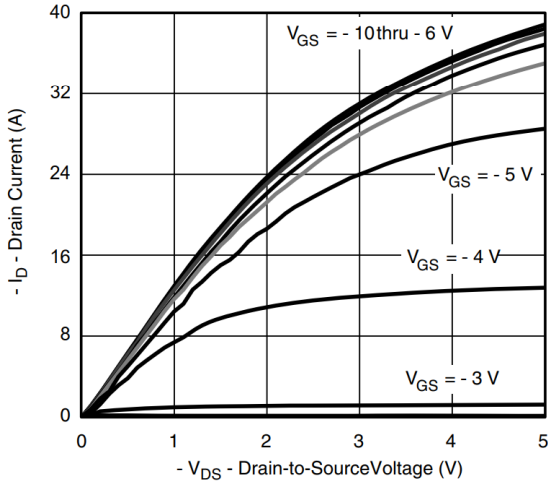
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0\text{ V}, I_D = -250\text{ }\mu\text{A}$	-200			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T$	$I_D = -250\text{ }\mu\text{A}$		-193		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			-5.2		
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$	-2		-4	V
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0\text{ V}, V_{GS} = \pm 20\text{ V}$			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -200\text{ V}, V_{GS} = 0\text{ V}$			-100	μA
		$V_{DS} = -160\text{ V}, V_{GS} = 0\text{ V}, T_J = 125\text{ }^\circ\text{C}$			-500	
Drain-Source On-State Resistance ^a	$R_{DS(on)}$	$V_{GS} = -10\text{ V}, I_D = -6\text{ A}$			0.5	Ω
Forward Transconductance ^a	g_{fs}	$V_{DS} = -50\text{ V}, I_D = -6\text{ A}$	4.5			S
Dynamic^b						
Input Capacitance	C_{iss}	$V_{DS} = -25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$		1230		μF
Output Capacitance	C_{oss}			390		
Reverse Transfer Capacitance	C_{rss}			85		
Total Gate Charge	Q_g	$V_{DS} = -160\text{ V}, V_{GS} = -10\text{ V}, I_D = -6\text{ A}$		32	45	nC
Gate-Source Charge	Q_{gs}			6		
Gate-Drain Charge	Q_{gd}			23		
Gate Resistance	R_g	$f = 1\text{ MHz}$		1.2		Ω
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -100\text{ V}, R_L = 10\text{ }\Omega$ $I_D = -6\text{ A}, V_{GEN} = -10\text{ V}, R_g = 9\text{ }\Omega$		15		ns
Rise Time	t_r			45		
Turn-Off Delay Time	$t_{d(off)}$			40		
Fall Time	t_f			36		
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I_S	$T_C = 25\text{ }^\circ\text{C}$			-10	A
Pulse Diode Forward Current ^a	I_{SM}				-40	
Body Diode Voltage	V_{SD}	$I_S = -6\text{ A}$			-5	V
Body Diode Reverse Recovery Time	t_{rr}	$I_F = -10\text{ A}, di/dt = 100\text{ A}/\mu\text{s}, T_J = 25\text{ }^\circ\text{C}$		205	330	ns
Body Diode Reverse Recovery Charge	Q_{rr}			3	4	μC
Reverse Recovery Fall Time	t_a			109		ns
Reverse Recovery Rise Time	t_b			116		

Notes:

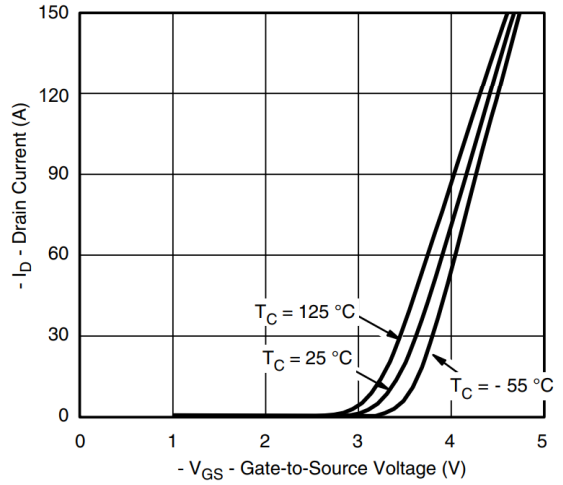
- Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

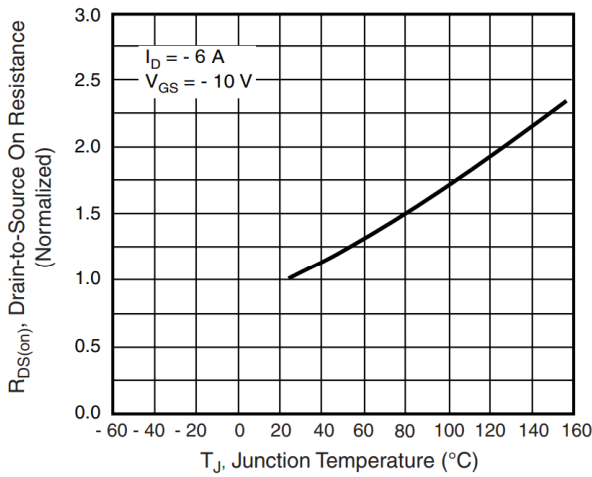
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



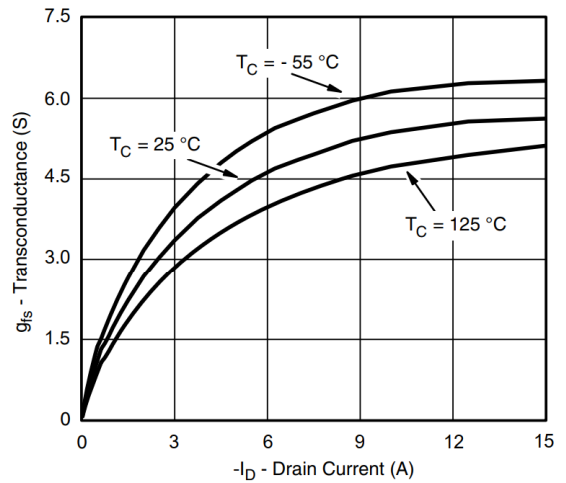
Output Characteristics



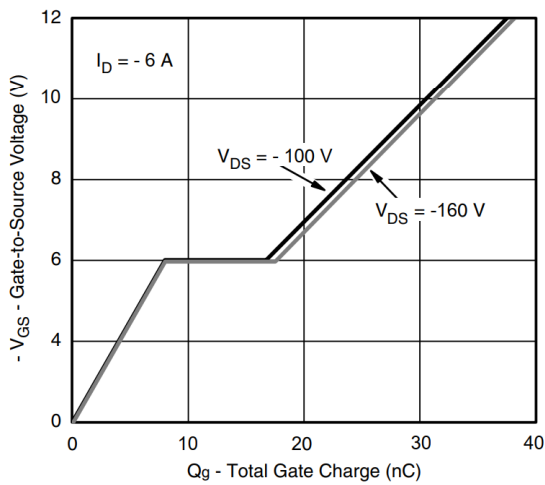
Transfer Characteristics



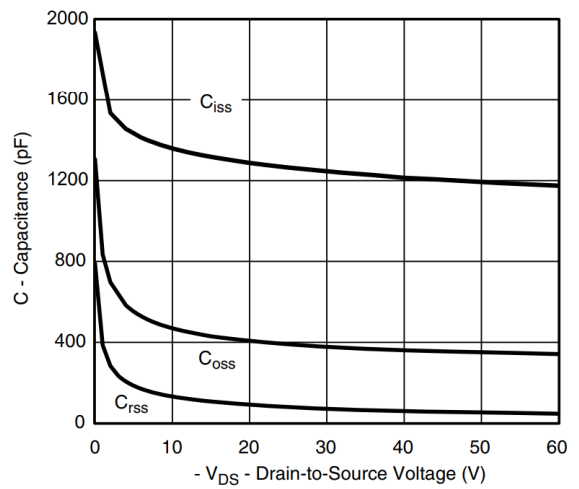
Normalized On-Resistance vs. Temperature



Transconductance

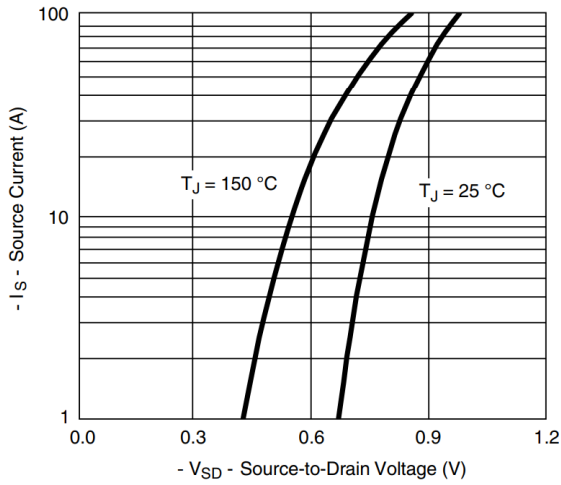


Gate Charge

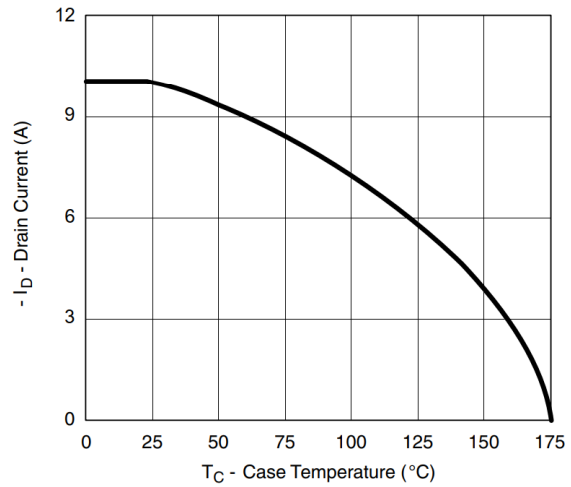


Capacitance

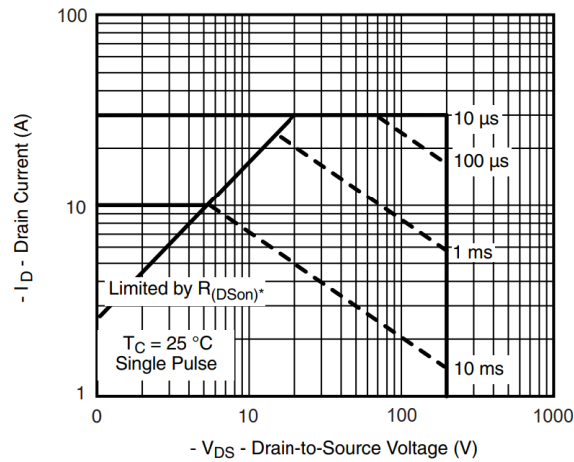
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Source-Drain Diode Forward Voltage

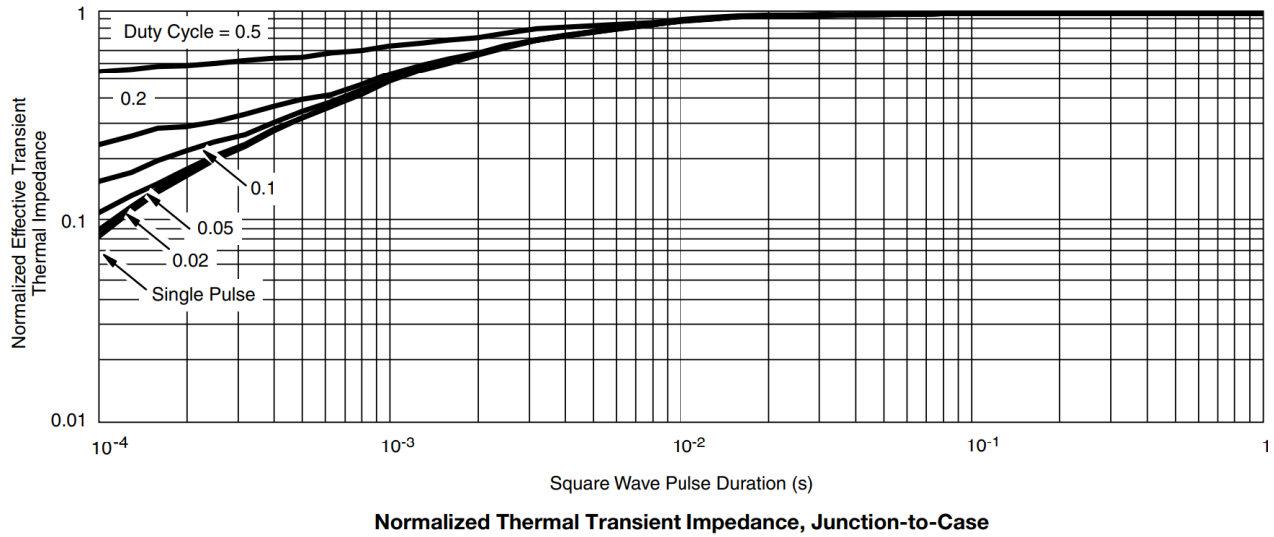


Maximum Avalanche and Drain Current vs. Case Temperature

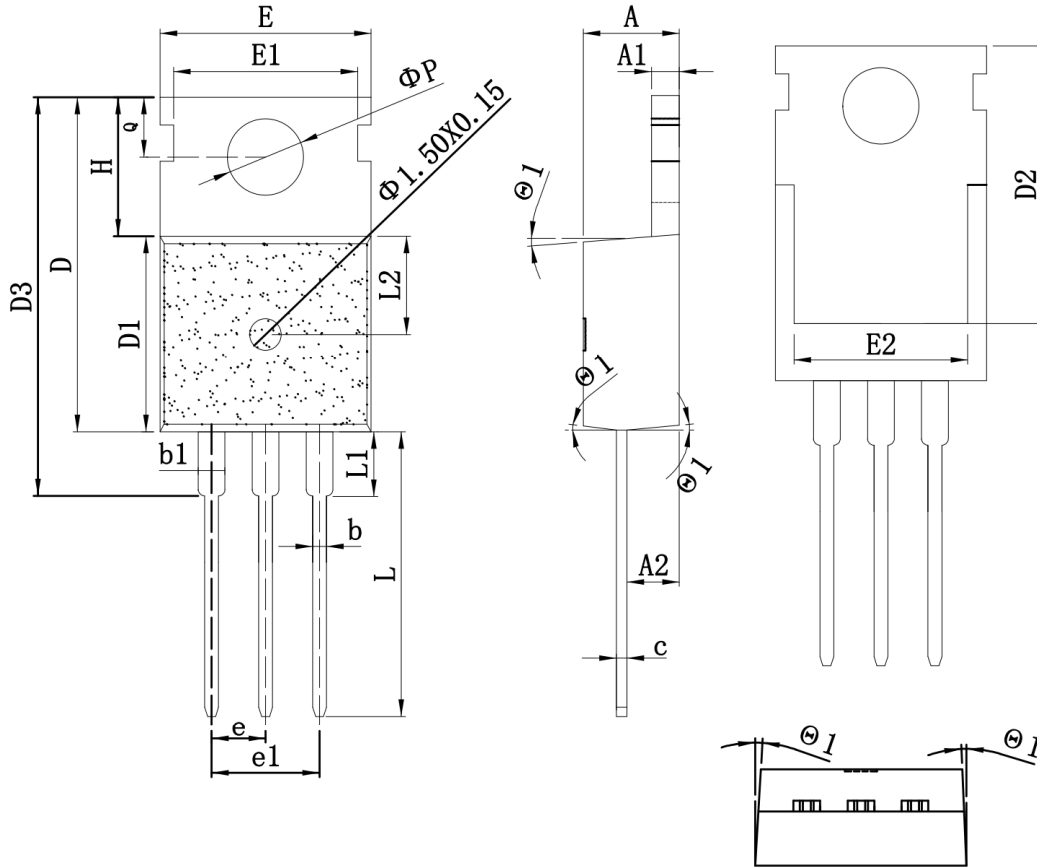


Maximum Safe Operating Area

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



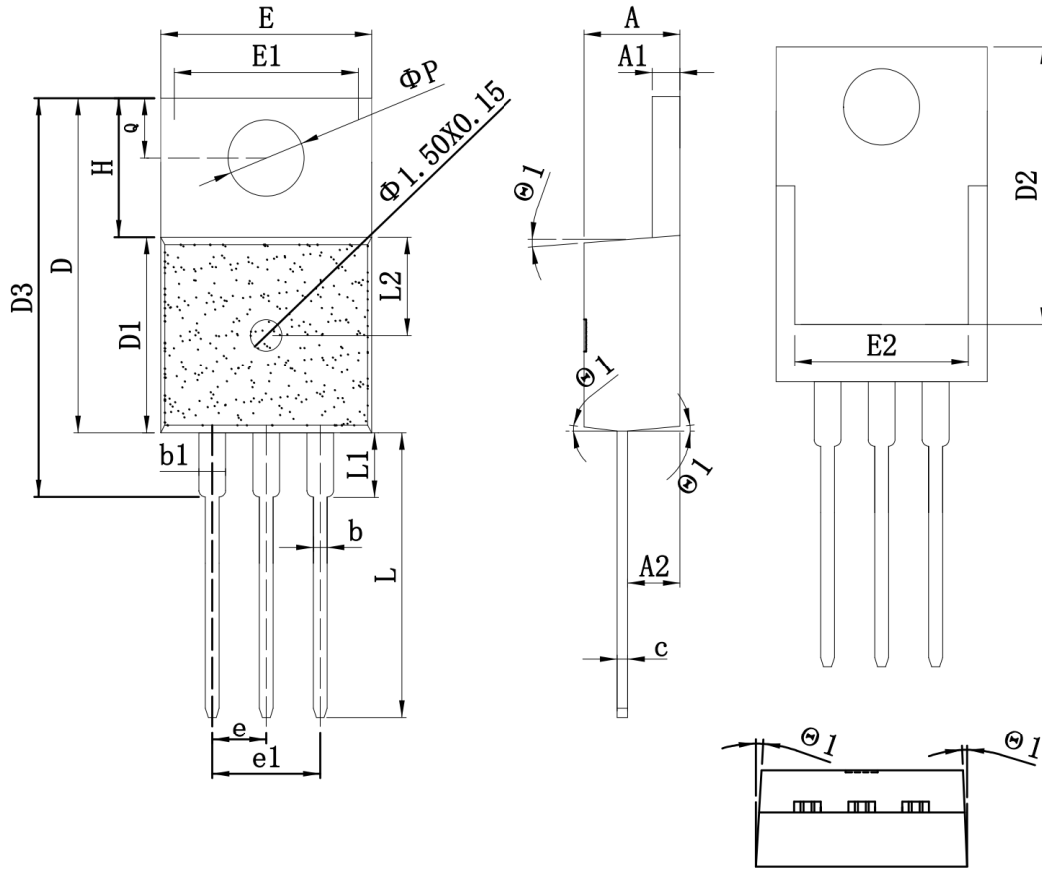
TO-220_3L-A PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm		
	MIN	TYP	MAX		MIN	TYP	MAX
A	4.15	4.50	4.80	E1	8.25	8.70	9.15
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80
A2	2.10	2.40	2.65	e	2.38	2.54	2.74
b	0.65	0.80	1.00	e1	5.08REF		
b1	1.10	1.33	1.80	H	6.20	6.50	6.90
c	0.35	0.50	0.65	L	12.75	13.28	13.70
D	14.25	15.75	16.15	L1	-	-	3.50
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00
D2	12.30	13.10	13.85	ϕP	3.40	3.65	3.85
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00
E	8.68	10.02	11.00	θ	2°	-	7°

TO-220_3L-B PACKAGE OUTLINE



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm		
	MIN	TYP	MAX		MIN	TYP	MAX
A	4.15	4.50	4.80	E1	8.25	8.70	9.15
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80
A2	2.10	2.40	2.65	e	2.38	2.54	2.74
b	0.65	0.80	1.00	e1	5.08REF		
b1	1.10	1.33	1.80	H	6.20	6.50	6.90
c	0.35	0.50	0.65	L	12.75	13.28	13.70
D	14.25	15.75	16.15	L1	-	-	3.50
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00
D2	12.30	13.10	13.85	ϕP	3.40	3.65	3.85
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00
E	8.68	10.02	11.00	θ	2°	-	7°

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